Written exam at the subject

SEMICONDUCTOR DEVICES

(ELEMENTI POLPREVODNIŠKE ELEKTRONIKE)

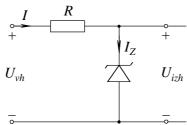
 I^{st} Bologna grade -2^{nd} year - Electronics - AE 26. 1. 2016

1. Determine semiconductor type for a sample/piece of crystalline Si, which contains homogeneously distributed acceptor impurities of the following concentration $N_A = 5 \times 10^{17}$ cm³. Calculate the energy difference (in eV) between the actual and intrinsic Fermi level and sketch energy band diagram. Calculate the specific conductivity of the sample.

(Data: T = 300 K, $\mu_n = 1300 \text{ cm}^2(\text{Vs})^{-1}$, $\mu_p = 450 \text{ cm}^2(\text{Vs})^{-1}$).

(Solution: p-type, $U_T = 25.88 \text{ mV}$; $E_F - E_{Fi} = -0.459 \text{ eV}$; $\sigma = 36 \text{ S/cm}$)

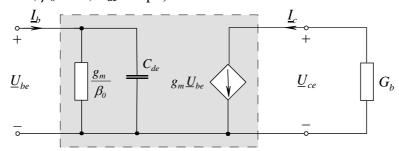
2. In a simple voltage stabilizer in the picture below specify the value of the resistor R so that at the input voltage $U_{vh} = 24$ V the current through the diode equals $I_Z = 10$ mA. The diode has parameters $U_{Z0} = 12$ V and $r_Z = 15$ Ω . Take both parameters into account and determine the value of the output voltage U_{izh} for the given input voltage.



(Solution: $R = 1185 \Omega$, $U_{izh} = 12,15 \text{ V}$)

3. Using the given model of a bipolar transistor at high frequencies, calculate the (absolute) value of the <u>current gain</u> of the transistor at the frequency f = 10 MHz.

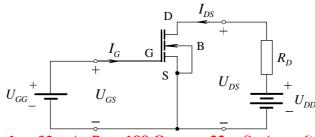
(Data: $g_m = 40 \text{ mS}$, $\beta_0 = 75$, $C_{de} = 6 \text{ pF}$).



(Solution: $|\underline{\beta}_f| = 61,2$)

4. In the given circuit with a MOS transistor determine the resistance R_D so that the output voltage U_{DS} equals to half of the supply voltage U_{DD} . Draw the equivalent circuit for small signals, determine the parameter g_{21} and calculate the voltage gain of the circuit, which is defined as the ratio of small amplitude AC component of output to input voltage $A_u = u_{ds}/u_{gs}$.

(Podatki: $U_{DD} = 12 \text{ V}$, $U_{GG} = 5 \text{ V}$, $U_T = 3 \text{ V}$, $C_0 \mu_n = 2 \text{ mAV}^{-2}$, W/L = 8)



(Solution: saturation, $I_D = 32 \text{ mA}$, $R_D = 188 \Omega$, $R_{21} = 32 \text{ mS}$, $R_u = -6$)

You have 60 minutes, you are allowed to use the sheet with basic formulas and constants. The results are expected to be communicated on tomorrow morning via e-mail.